

## Honeywell Sensing and Control



Home > Products > Emitter > Infrared Emitting Diode > Product Page

### SE1450-003L

#### Order Product and Get Support

- U.S. Authorized Distributors
- Global Sales & Service
- N. American Sales Reps
- Distributor Inventory
- Technical Assistance
- White Papers
- Literature Request
- RoHS Product List
- Customer Feedback



#### SE Series GaAs Infrared Emitting Diode, Metal Can Coaxial Package

Actual product appearance may vary.

#### Features

- Compact, metal can coaxial package
- 24 ° (nominal) beam angle
- 935 nm wavelength
- Wide operating temperature range [-55 °C to 125 °C]
- Mechanically and spectrally matched to SD1420 photodiode, SD1440 phototransistor and SD1410 photodarlington

#### Description

The SE1450 is a gallium arsenide infrared emitting diode mounted in a glass lensed, metal can coaxial package. The package may have a tab or second lead welded to the can as an optional feature (SE1450-XXXL). Both leads are flexible and may be formed as required to fit various mounting configurations.

#### Supporting Documentation

▶ [Dimensions](#)

▶ [Schematic](#)

▶ [Performance Charts](#)

▶ [Engineering Drawing](#)

#### My Links

- [Login to iCOM](#)
- [Login as Rep/AD](#)
- [Login as Guest](#)
- [Login to Digital University](#)

#### Keyword Search

Search for product and support information.

#### Product Search

Part number search:

Use (\*) to expand search

→ [Specification Search](#)

#### Product Specifications

|                           |                         |
|---------------------------|-------------------------|
| Series Name               | Infrared Emitting Diode |
| Product Type              | IR Component            |
| Power Output              | 0.70 mW min             |
| Beam Angle (Degree)       | 24                      |
| Package Style             | Coaxial, Lead Case      |
| Package Components        | Metal                   |
| Forward Current           | 50 mA                   |
| Forward Voltage           | 1.6 V                   |
| Reverse Breakdown Voltage | 3 V                     |
| Output Wavelength         | 935 nm                  |

|                                 |                                     |
|---------------------------------|-------------------------------------|
| Spectral Bandwidth              | 50 nm                               |
| Spectral Shift With Temperature | 0.3 nm/°C                           |
| Rise and Fall Time              | 0.7 μs                              |
| Power Dissipation               | 75 mW                               |
| Operating Temperature Range     | -55 °C to 125 °C [-67 °F to 257 °F] |
| Availability                    | Global                              |

[Terms & Conditions](#) | [Privacy Statement](#) | [Site Map](#)